

2 Ω , Quad, SPST, CMOS Analog Switches

ABSOLUTE MAXIMUM RATINGS

V+ to GND	-0.3V to +12V
V- to GND	+0.3V to -12V
V+ to V-	+12V
V _L , IN ₋ to GND (Note 1)	-0.3V to (V+ + 0.3V)
V _{COM} -, V _{NC} -, V _{NO} - (Note 1)	V- to V+
Current (any terminal)	±50mA
Continuous Current (COM ₋ , NC ₋ , NO ₋)	±100mA
Peak Current (COM ₋ , NC ₋ , NO ₋ pulsed at 1ms 10% duty cycle)	±200mA

Continuous Power Dissipation (T _A = +70°C)	
16-Pin Plastic DIP (derate 10.5mW/°C above +70°C)	842mW
16-Pin TSSOP (derate 5.7mW/°C above +70°C)	457mW
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on NC₋, NO₋, COM₋, or IN₋ exceeding V+ or V- are clamped by internal diodes. Limit forward diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +5V ±10%, V- = -5V ±10%, V_L = +2.7V to V+, GND = 0, V_{IH} = +2.4V, V_{IL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range	V _{COM} -, V _{NO} -, V _{NC} -			V-		V+	V
On-Resistance	R _{ON}	V+ = 4.5V, V- = -4.5V, I _{COM} - = 50mA, V _{NO} - or V _{NC} - = ±3.3V	T _A = +25°C	1.2	1.6	Ω	
			T _A = T _{MIN} to T _{MAX}		2		
On-Resistance Match Between Channels (Note 3)	ΔR _{ON}	V+ = 4.5V, V- = -4.5V, I _{COM} - = 50mA, V _{NO} - or V _{NC} - = ±3.3V	T _A = +25°C	0.2	0.3	Ω	
			T _A = T _{MIN} to T _{MAX}		0.5		
On-Resistance Flatness (Note 4)	R _{FLAT}	V+ = 4.5V, V- = -4.5V, I _{COM} - = 50mA, V _{NO} - or V _{NC} - = ±3.3V, 0	T _A = +25°C	0.2	0.4	Ω	
			T _A = T _{MIN} to T _{MAX}		0.5		
NC_- or NO_- Off-Leakage Current (Note 5)	I _N (OFF)	V+ = +5.5V, V- = -5.5V, V _{NO} - or V _{NC} - = ±4.5V, V _{COM} - = ∓4.5V	T _A = +25°C	-1	0.1	1	nA
			T _A = T _{MIN} to T _{MAX}	-10		10	
COM_- Off-Leakage Current (Note 5)	I _{COM} (OFF)	V+ = +5.5V, V- = -5.5V, V _{NO} - or V _{NC} - = ±4.5V, V _{COM} - = ∓4.5V	T _A = +25°C	-1	0.1	1	nA
			T _A = T _{MIN} to T _{MAX}	-10		10	
COM_- On-Leakage Current (Note 5)	I _{COM} (ON)	V+ = +5.5V, V- = -5.5V, V _{COM} - = ±4.5V, V _{NO} - or V _{NC} - = ±4.5V or floating	T _A = +25°C	-2	0.2	2	nA
			T _A = T _{MIN} to T _{MAX}	-25		25	
LOGIC INPUT							
Input Logic High	V _{IH}	V _L = V+		2.4			V
Input Logic Low	V _{IL}	V _L = V+				0.8	V
Input Leakage Current	I _{IN}	V _L = V+		-1	0.005	1	μA

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MAX4677/MAX4678/MAX4679

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = +5V $\pm$ 10%, V- = -5V $\pm$ 10%, VL = +2.7V to V+, GND = 0, VIH = +2.4V, VIL = +0.8V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at TA = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
Positive Supply Voltage	V+		+2.7		+5.5	V
Negative Supply Voltage	V-		-2.7		-5.5	V
Logic Supply Voltage	VL		2.7		V+	V
Positive Supply Current	I+	IN_ = GND or VL		0.001	1	μ A
Negative Supply Current	I-	IN_ = GND or VL			-1	μ A
Logic Supply Current	IL	IN_ = GND or VL			1	μ A
Ground Current	IGND	IN_ = 0 or V+, V+ = 5.5V, V- = -5.5V			1	μ A
DYNAMIC						
Turn-On Time	tON	V+ = +4.5V, V- = -4.5V, VNC_ or VNO_ = $\pm$ 3.3V, VL = V+, Figure 2	TA = +25°C	200	350	ns
			TA = TMIN to TMAX		500	
Turn-Off Time	tOFF	V+ = +4.5V, V- = -4.5V, VNC_ or VNO_ = $\pm$ 3.3V, VL = V+, Figure 2	TA = +25°C	110	150	ns
			TA = TMIN to TMAX		350	
Break-Before-Make Delay	tBBM	Figure 3, MAX4679 only, RL = 300 Ω , CL = 35pF	5			ns
Charge Injection	Q	RGEN = 0, CL = 1nF, VGEN = 0, Figure 4		85		pC
Off-Isolation	VISO	RL = 50 Ω , CL = 5pF, f = 1MHz, Figure 5a		-65		dB
Crosstalk		RL = 50 Ω , CL = 5pF, f = 1MHz, Figure 6a		-84		dB
-3dB Bandwidth	BW	RS = 50 Ω , RL = 50 Ω , Figure 7a		66		MHz
NC or NO Off-Capacitance	C(N_OFF)	f = 1MHz, Figure 8		85		pF
COM Off-Capacitance	C(COMOFF)	f = 1MHz, Figure 8		85		pF
On-Capacitance	C(ON)	f = 1MHz, Figure 8		350		pF

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ELECTRICAL CHARACTERISTICS—Single Supply

(V₊ = +5V $\pm$ 10%, V₋ = 0, V_L = +2.7V to V₊, GND = 0, V_{IH} = +2.4V, V_{IL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Input Voltage Range	V _{COML} , V _{NO-} , V _{NC-}			0		V+	V
On-Resistance	R _{ON}	V+ = +4.5V, I _{COML} = 50mA, V _{NO-} or V _{NC-} = 3.3V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	1.8	2.7	3.5	Ω
On-Resistance Match Between Channels (Note 3)	ΔR _{ON}	V+ = +4.5V, I _{COML} = 50mA, V _{NO-} or V _{NC-} = 3.3V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	0.05	0.15	0.3	Ω
On-Resistance Flatness (Note 4)	R _{FLAT}	V+ = +4.5V, I _{COML} = 50mA, V _{NO-} or V _{NC-} = 3.3V, 1.5V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	0.15	0.25	0.4	Ω
NC_ or NO_ Off- Leakage Current (Note 5)	I _{N(OFF)}	V+ = +5.5V; V _{NO-} or V _{NC-} = 4.5V, 1V; V _{COML} = 1V, 4.5V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	-1	0.1	1	nA
COM_ Off-Leakage Current (Note 5)	I _{COM(OFF)}	V+ = +5.5V; V _{NO-} or V _{NC-} = 4.5V, 1V; V _{COML} = 1V, 4.5V	T _A = +25°C T _A = T _{MIN} to T _{MAX}	-1	0.1	1	nA
COM_ On-Leakage Current (Note 5)	I _{COM(ON)}	V+ = +5.5V; V _{COML} = 1V, 4.5V; V _{NO-} or V _{NC-} = 1V, 4.5V, or floating	T _A = +25°C T _A = T _{MIN} to T _{MAX}	-2	0.2	2	nA
LOGIC INPUT							
Input Low Voltage	V _{IL}	V _L = V+				0.8	V
Input High Voltage	V _{IH}	V _L = V+		2.4			V
Input Leakage Current	I _{IN}	V _L = V+		-1	0.005	1	μA
POWER SUPPLY							
Positive Supply Voltage	V+			2.7		6	V
Logic Supply Voltage	V _L			2.7		V+	V
Positive Supply Current	I+	V _{IN-} = 0 or V _L , V _L = V+			1	1	μA
Logic Supply Current	I _L	V _{IN-} = 0 or V _L , V+ = 5.5V				1	μA
Ground Current	I _{GND}	V _{IN-} = 0 or V _L , V+ = 5.5V			1	10	μA
DYNAMIC							
Turn-On Time	t _{ON}	V _L = V+, V+ = +4.5V; V _{NC-} or V _{NO-} = 3.3V, R _L = 300Ω, C _L = 35pF, Figure 2	T _A = +25°C T _A = T _{MIN} to T _{MAX}	600	1000	1400	ns
Turn-Off Time	t _{OFF}	V _L = V+, V+ = +4.5V; V _{NC-} or V _{NO-} = 3.3V, R _L = 300Ω, C _L = 35pF, Figure 2	T _A = +25°C T _A = T _{MIN} to T _{MAX}	120	165	400	ns

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ELECTRICAL CHARACTERISTICS—Single Supply (continued)

($V_+ = +5V \pm 10\%$, $V_- = 0$, $V_L = +2.7V$ to V_+ , $GND = 0$, $V_{IH} = +2.4V$, $V_{IL} = +0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25^\circ C$.) (Note 2)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Break-Before- Make Delay	t_{BBM}	MAX4679 only, $R_L = 300\Omega$, $C_L = 35pF$, Figure 3	5			ns
Charge Injection	Q	$R_{GEN} = 0$, $C_L = 1nF$, $V_{GEN} = 0$, Figure 4		9		pC
Off-Isolation	V_{ISO}	$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 5b		-65		dB
Crosstalk		$R_L = 50\Omega$, $C_L = 5pF$, $f = 1MHz$, Figure 6b		-84		dB
-3dB Bandwidth	BW	$R_S = 50\Omega$, $R_L = 50\Omega$, Figure 7b		63		MHz
NC or NO Off-Capacitance	$C_{(N_OFF)}$	$f = 1MHz$, Figure 8		85		pF
COM Off-Capacitance	$C_{(COMOFF)}$	$f = 1MHz$, Figure 8		85		pF
On-Capacitance	$C_{(ON)}$	$f = 1MHz$, Figure 8		350		pF

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

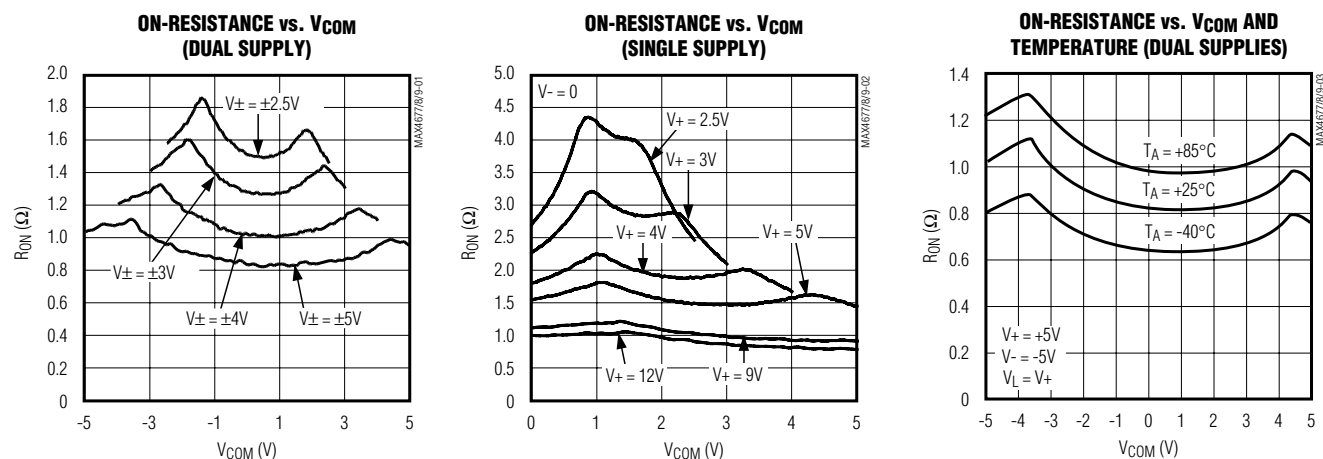
Note 3: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

Note 4: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 5: Leakage parameters are 100% tested at maximum-rated hot operating temperature and the highest supply voltage, and guaranteed by correlation at $+25^\circ C$.

Typical Operating Characteristics

($T_A = +25^\circ C$, unless otherwise noted.)

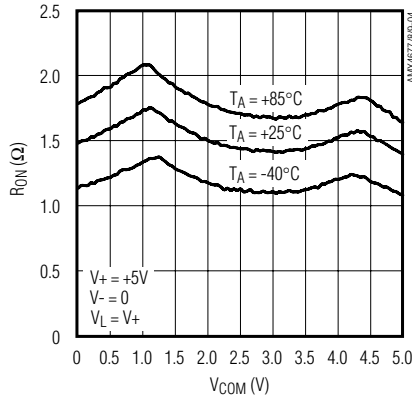


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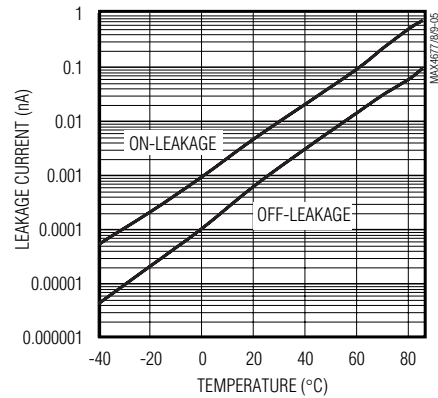
Typical Operating Characteristics (continued)

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

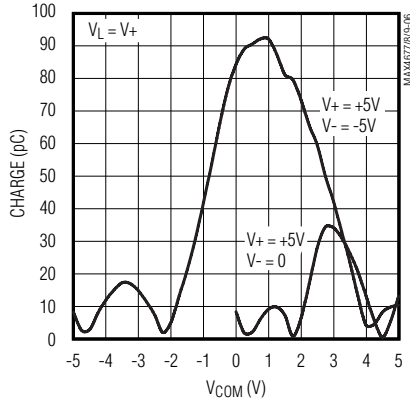
ON-RESISTANCE vs. V_{COM} AND TEMPERATURE (SINGLE SUPPLY)



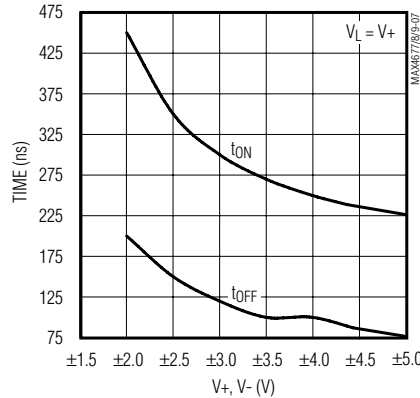
ON/OFF-LEAKAGE CURRENT vs. TEMPERATURE



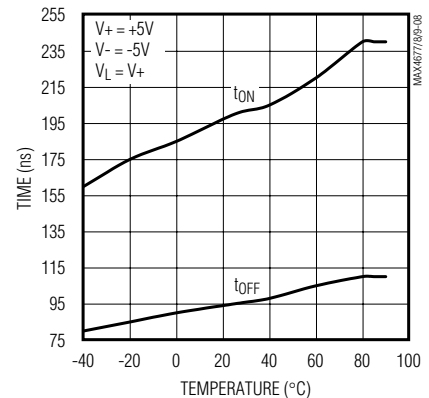
CHARGE INJECTION vs. V_{COM}



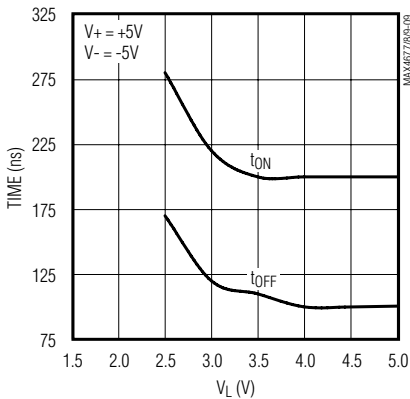
t_{ON} , t_{OFF} vs. SUPPLY VOLTAGE (DUAL SUPPLIES)



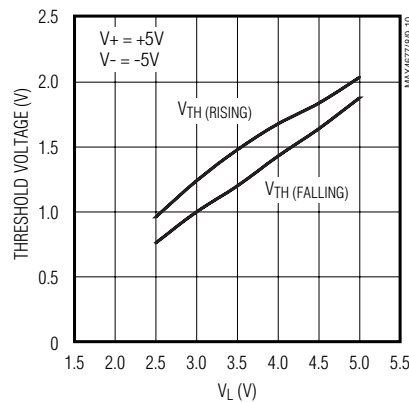
t_{ON} , t_{OFF} vs. TEMPERATURE



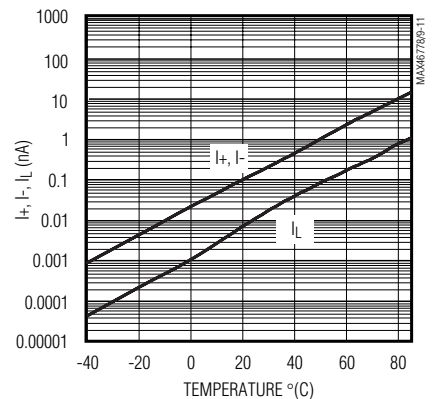
t_{ON} , t_{OFF} vs. LOGIC SUPPLY



INPUT THRESHOLD vs. LOGIC SUPPLY



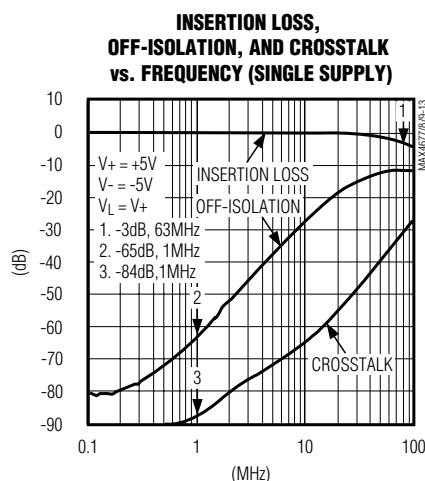
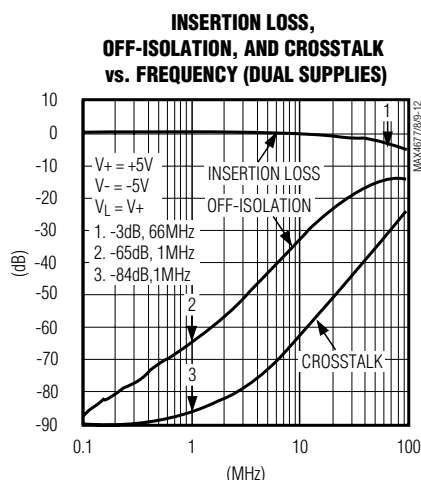
POWER-SUPPLY CURRENT vs. TEMPERATURE



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Typical Operating Characteristics (continued)

(T_A = +25°C, unless otherwise noted.)



Pin Description

PIN			NAME	FUNCTION
MAX4677	MAX4678	MAX4679		
1, 8, 9, 16	1, 8, 9, 16	1, 8, 9, 16	IN1, IN2, IN3, IN4	Logic Inputs
2, 7, 10, 15	2, 7, 10, 15	2, 7, 10, 15	COM1, COM2, COM3, COM4	Analog Switch Common Terminals
3, 6, 11, 14	—	—	NC1, NC2, NC3, NC4	Analog Switch Normally Closed Terminals
—	3, 6, 11, 14	—	NO1, NO2, NO3, NO4	Analog Switch Normally Open Terminals
—	—	3, 6	NO1, NO4	Analog Switch Normally Open Terminals
—	—	11, 14	NC2, NC3	Analog Switch Normally Closed Terminals
4	4	4	V ₋	Negative Supply-Voltage Input. Connect to GND for single-supply operation.
5	5	5	GND	Ground
12	12	12	V _L	Logic Supply Input
13	13	13	V ₊	Positive Supply Input

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Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V₊ on first, then V₋, then V_L followed by the logic inputs, NO₋, NC₋, or COM. If proper power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins, and a Schottky diode between V₊ and V_L for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V₊ and one diode drop above V₋, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V₊ and V₋ should not exceed 11V.

Power-supply bypassing improves noise margin and prevents switching noise from propagating from the V₊ supply to other components. A 0.1μF capacitor connected from V₊ to GND is adequate for most applications.

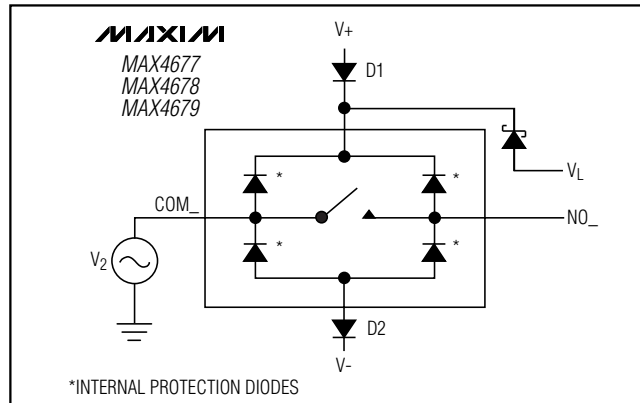


Figure 1. Overvoltage Protection Using External Blocking Diodes

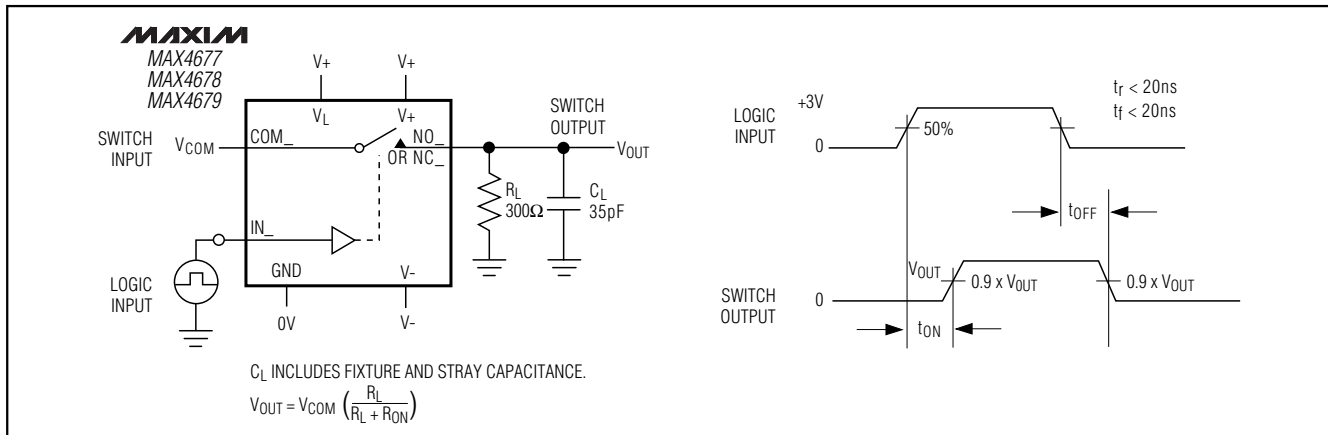


Figure 2. Switching Time

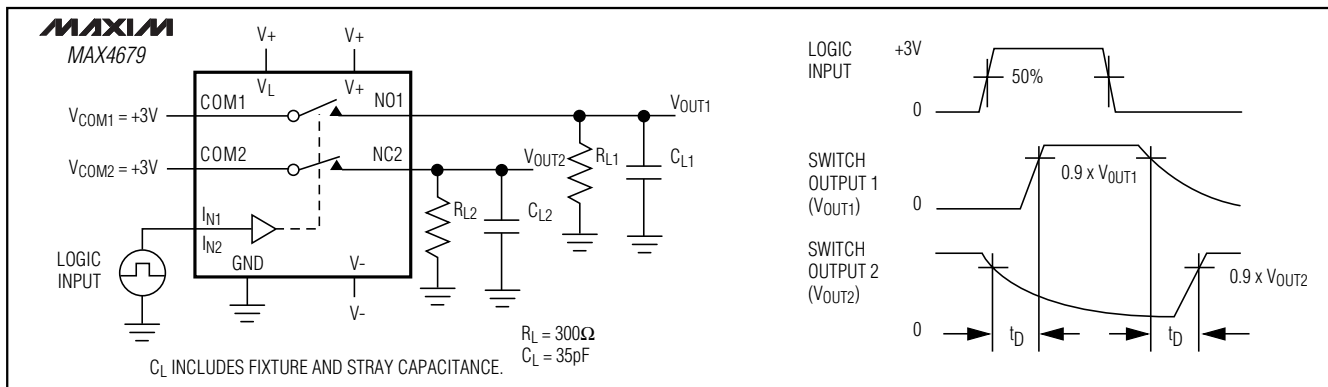


Figure 3. Break-Before-Make Interval (MAX4679 Only)

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MAX4677/MAX4678/MAX4679

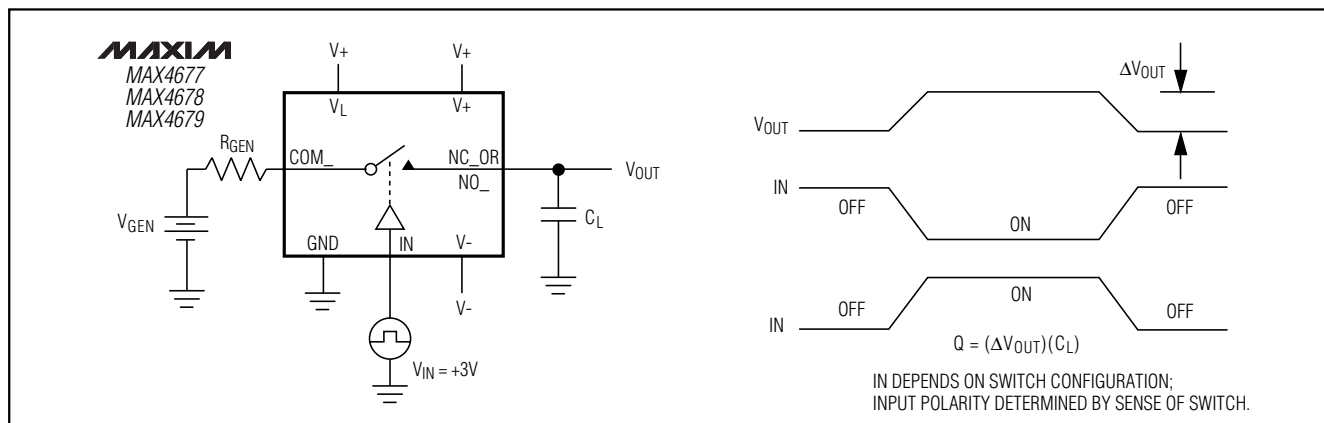


Figure 4. Charge Injection

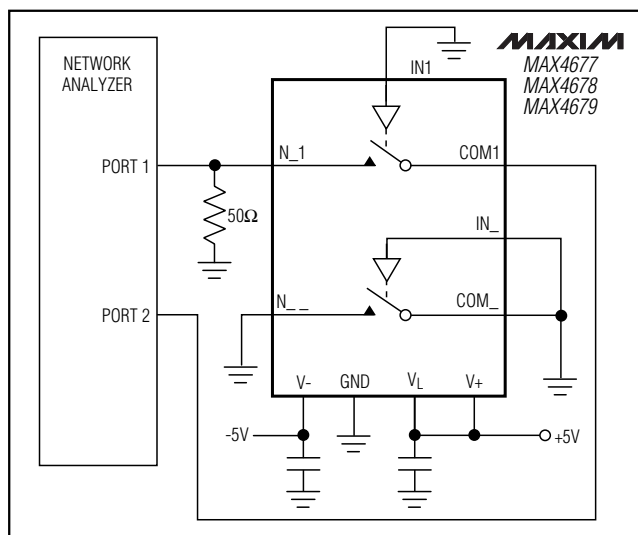


Figure 5a. Off-Isolation Test Circuit, Dual Supplies

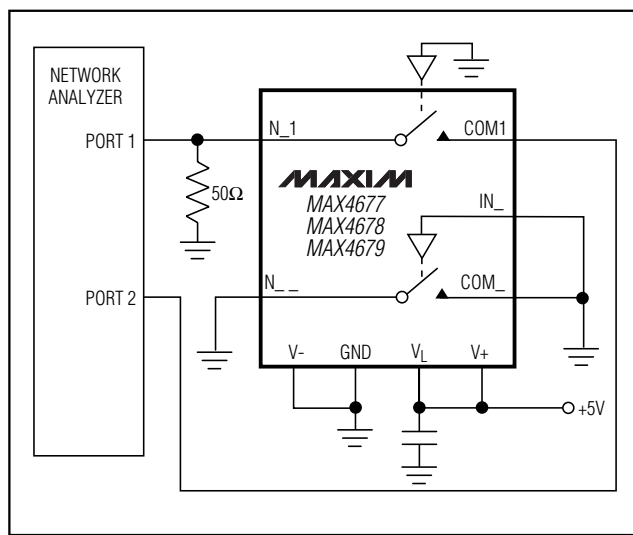


Figure 5b. Off-Isolation Test Circuit, Single Supply

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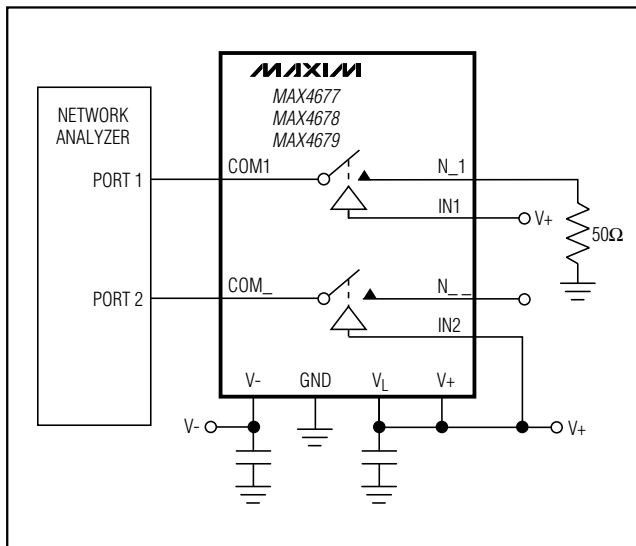


Figure 6a. Crosstalk Test Circuit, Dual Supplies

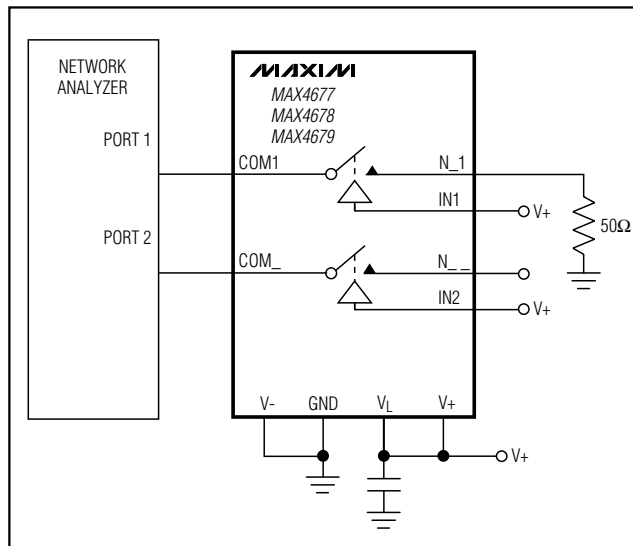


Figure 6b. Crosstalk Test Circuit, Single Supply

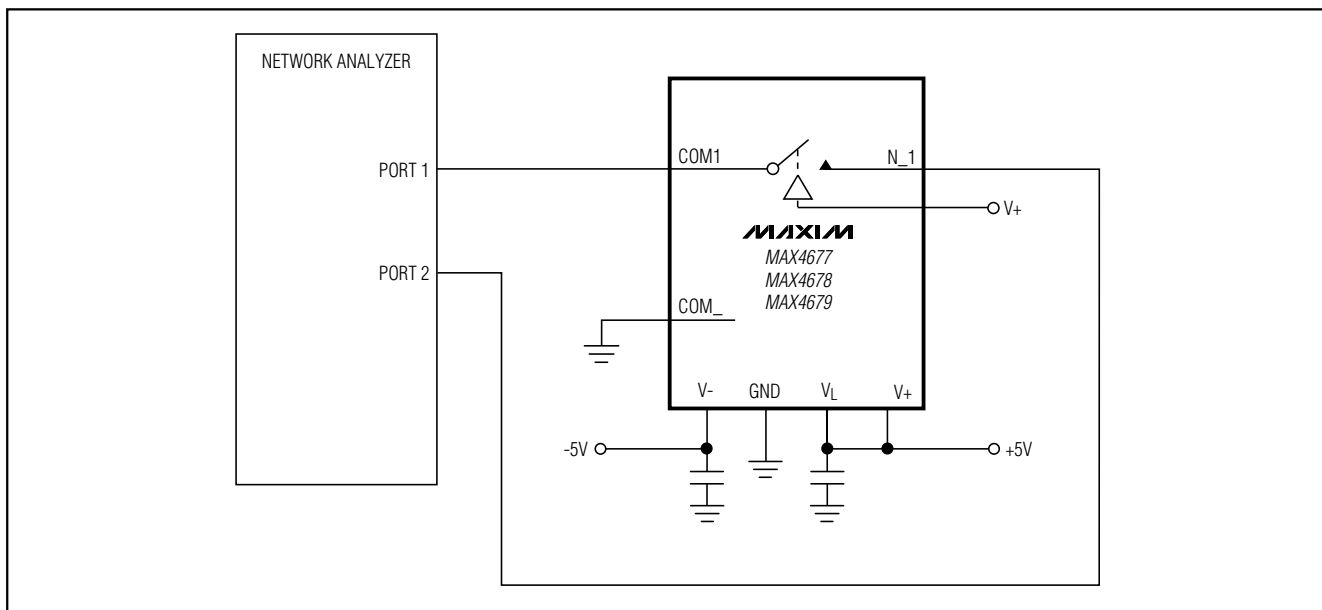


Figure 7a. Insertion Loss Test Circuit, Dual Supplies

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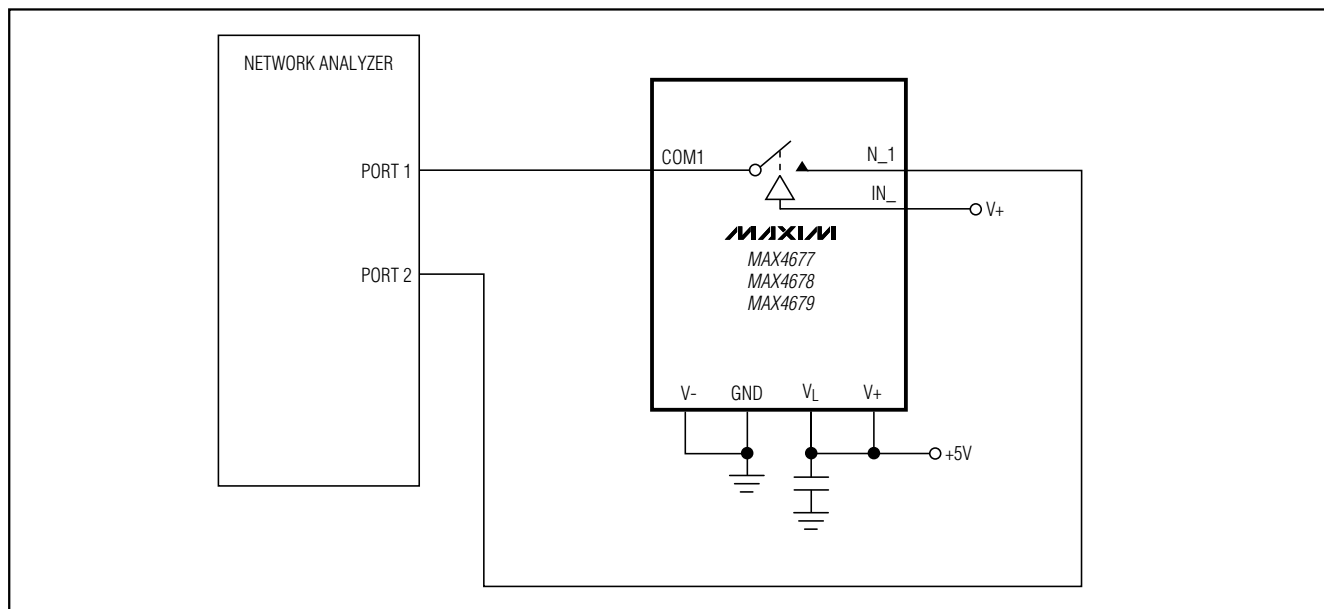


Figure 7b. Insertion Loss Test Circuit, Single Supply

Chip Information

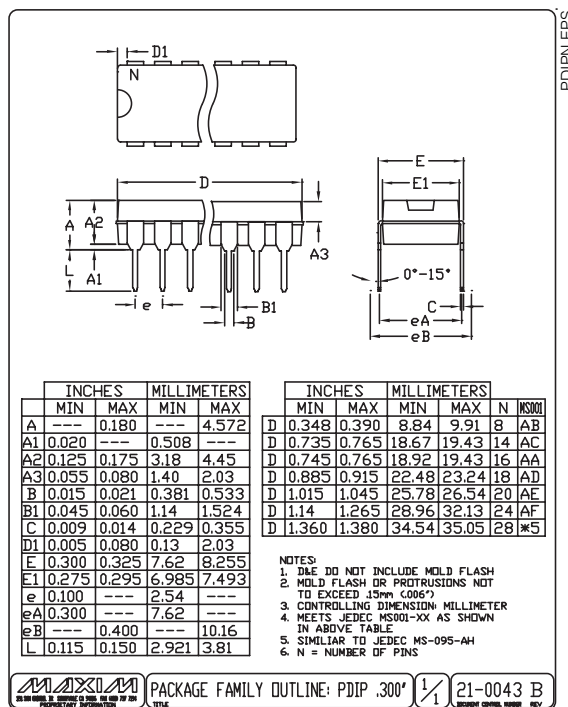
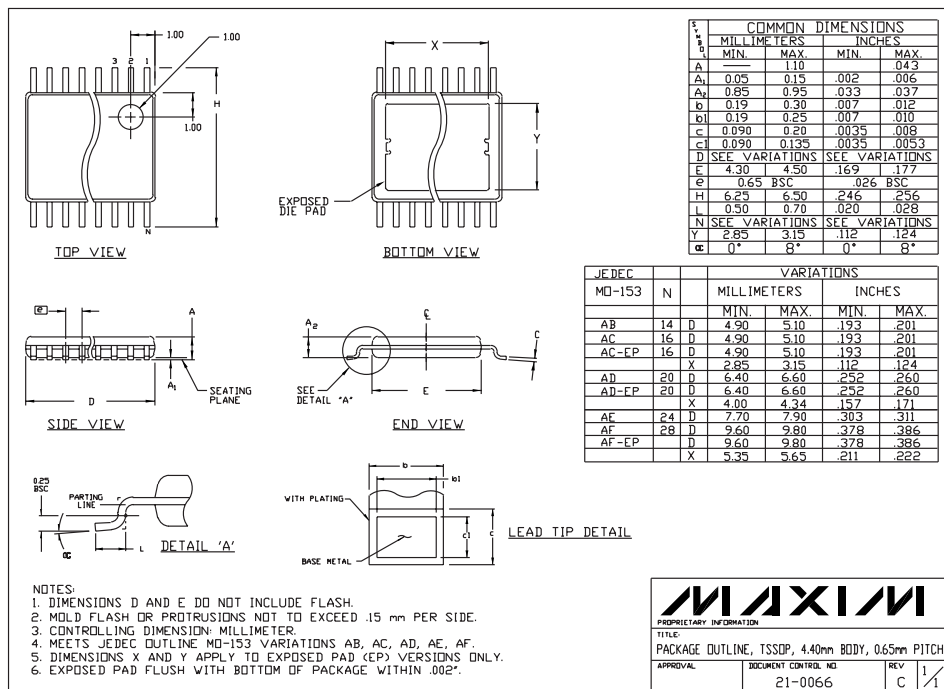
TRANSISTOR COUNT: 240

PROCESS: CMOS

MAX4677/MAX4678/MAX4679

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Package Information



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